

Tinghui Li

List of Publications by Year in descending order

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19

papers

429

citations

1163117

8

h-index

839539

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19

all docs

19

docs citations

19

times ranked

712

citing authors

#	ARTICLE	IF	CITATIONS
1	Strain-regulated electronic structure for hydrogen evolution reaction in Fe ₃ S ₄ monolayer. Physics Letters, Section A: General, Atomic and Solid State Physics, 2020, 384, 126368.	2.1	3
2	Magnetism in alkali-metal-doped wurtzite semiconductor materials controlled by strain engineering. Journal of Applied Physics, 2016, 120, 125101.	2.5	2
3	Optical identification of oxygen vacancy types in SnO ₂ nanocrystals. Applied Physics Letters, 2013, 102, .	3.3	65
4	Enhanced Photocatalytic Oxygen Evolution by Crystal Cutting. Advanced Materials, 2013, 25, 2035-2039.	21.0	49
5	Compositional dependence of Raman frequencies in Si _x Ge _{1-x} alloys. Journal of Semiconductors, 2012, 33, 112001.	3.7	5
6	Electronic structure and optical properties of $\hat{\ell}^2$ -FeSi ₂ (100)/Si(001) interface at high pressure. Applied Physics Letters, 2012, 101, 111909.	3.3	2
7	Oxygen-vacancy and depth-dependent violet double-peak photoluminescence from ultrathin cuboid SnO ₂ nanocrystals. Applied Physics Letters, 2012, 100, 121903.	3.3	45
8	Identification of oxygen vacancy types from Raman spectra of SnO ₂ nanocrystals. Journal of Raman Spectroscopy, 2012, 43, 1423-1426.	2.5	172
9	Si _x optical phonon behavior in localized Si clusters of Si _x Ge _{1-x} alloy nanocrystals. Applied Physics A: Materials Science and Processing, 2011, 103, 361-365.	2.3	4
10	Surface carbon layer and visible-light photocatalytic activities of carbon-coated TiO ₂ nanotubes synthesized in organic electrolytes. Applied Physics A: Materials Science and Processing, 2011, 105, 703-707.	2.3	7
11	Morphology-dependent low-frequency Raman scattering in ultrathin spherical, cubic, and cuboid SnO ₂ nanocrystals. Applied Physics Letters, 2011, 99, 251902.	3.3	7
12	The physics network teaching system design and implementation based on constructivism. , 2011, ,.		1
13	Twinning Ge _{0.54} Si _{0.46} nanocrystal growth mechanism in amorphous SiO ₂ films. Applied Physics Letters, 2010, 96, .	3.3	13
14	Photoluminescence from colloids containing aluminum hydroxide nanocrystals with uniform size. Applied Physics Letters, 2010, 97, 121901.	3.3	10
15	Ordered amorphous silicon nanoisland arrays and reflection spectral dependence on nanoisland geometrical parameters. Applied Physics Letters, 2009, 94, 151903.	3.3	8
16	Raman investigation of oxidation mechanism of silicon nanowires. Applied Physics Letters, 2009, 95, .	3.3	14
17	Damping of surface acoustic vibration induced by electrons trapped on SnO ₂ nanocrystal surface. Applied Physics Letters, 2009, 95, 211903.	3.3	6
18	Surface-polarization-induced formation of amorphous foliaceous SiO ₂ helical nanobelts. Applied Physics Letters, 2009, 94, 253110.	3.3	5

#	ARTICLE	IF	CITATIONS
19	Influence of GeSi interfacial layer on Ge–Ge optical phonon mode in SiO ₂ films embedded with Ge nanocrystals. <i>Applied Physics Letters</i> , 2009, 95, .	3.3	11